



# Light ion irradiation-induced phase transformation in the monoclinic polymorph of zirconia

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## ABSTRACT

Ion irradiation damage experiments were performed at  $\sim 80$  K on polycrystalline samples of monoclinic, slightly sub-stoichiometric zirconia ( $ZrO_{1.98}$ ). Following irradiation with 150 keV  $Ne^+$  ions, the monoclinic phase was gradually replaced by a new phase. Transmission electron microscopy (TEM) observations in cross-sectional geometry and electron microdiffraction ( $\mu D$ ) measurements revealed that the irradiated layer in a sample irradiated to a fluence of  $5 \times 10^{20}$   $Ne/m^2$  is partially transformed to a higher symmetry phase of high crystallinity. This phase transformation is accompanied by reduction of the initial micron-sized, highly-twinned grain distribution, to a nano-phased grain structure. Grazing incidence X-ray diffraction (GIXRD) measurements revealed that the radiation-induced phase is a tetragonal polymorph of zirconia. This was verified by the existence of strong (101) diffraction maxima and weak (102) reflections (body-centered cell). Raman spectroscopy (RS) measurements were also performed in an attempt to corroborate GIXRD results obtained from the irradiated material. RS measurements in the confocal geometry agreed with GIXRD measurements, although RS was not as definitive as GIXRD. In addition to RS showing the existence of a band corresponding to a tetragonal structure at  $262\text{ cm}^{-1}$ , a new mystery band appeared at  $702\text{ cm}^{-1}$  that increased in intensity as a function of irradiation fluence.

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## 1. Introduction

Zirconia (zirconium dioxide, nominally with stoichiometry  $ZrO_2$ ) has long attracted the interest of scientists and engineers because of its important ceramic properties. It is one of the most refractory of all oxide compounds and it exhibits both high thermal shock and corrosion resistance [1]. Zirconia also exists in three crystallographic modifications as a function of temperature at atmospheric pressure [2]:



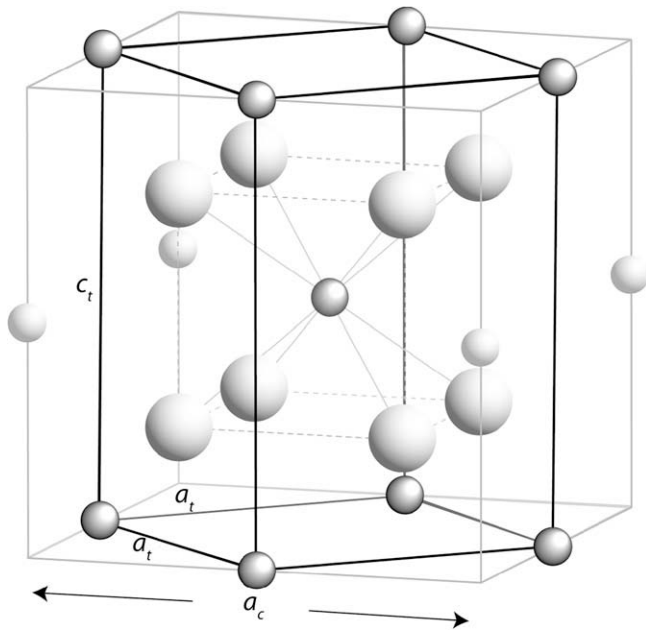
The tetragonal-to-monoclinic transformation shown above has been exploited in  $ZrO_2$ -containing ceramics that are ‘transformation toughened’ [3].

The monoclinic phase of zirconia ( $m\text{-}ZrO_2$ ) is often referred to by its mineralogical name, baddeleyite, and belongs to space group  $P2_1/c$  (S.G. # 14). Tetragonal zirconia ( $t\text{-}ZrO_2$ ) is described in the literature using either a body-centered tetragonal ( $bct$ ) or face-centered tetragonal ( $ftc$ ) unit cell. In this paper, we will adopt the  $bct$  description (Fig. 1). The space group for  $t\text{-}ZrO_2$  is  $P4_2/nmc$  (S.G. # 137) with Zr atoms occupying the  $2a$  Wyckoff equipoint

and O atoms occupying the  $4d$  equipoint in the 1st setting for this space group. The structure of  $t\text{-}ZrO_2$  was first refined by Teufer [4] and has come to be known as the ‘Teufer’ structure for tetragonal phase  $ZrO_2$ .

Several recent radiation damage studies of zirconia have revealed that polymorphism plays a significant role in the radiation damage evolution of  $ZrO_2$ . Sickafus et al. [5] found, based on transmission electron microscopy observations, that monoclinic zirconia ( $m\text{-}ZrO_2$ ) exposed to 340 keV  $Xe^{++}$  ions (in the nuclear stopping energy regime) at 120 K, transformed to a higher symmetry phase, either  $t\text{-}ZrO_2$  or cubic ( $c\text{-}ZrO_2$ ), by a peak displacement damage dose between 2 and 20 displacements per atom (dpa). This crystalline phase was reported to resist further transformation (especially amorphization) to a peak dose of more than 100 dpa [5–6]. Simeone et al. [7] observed a similar transformation of  $m\text{-}ZrO_2$  to the  $t\text{-}ZrO_2$  polymorph (heretofore denoted as an  $m\text{-}t$  transformation), under primarily nuclear stopping conditions using 800 keV Bi ions. Simeone et al. [7] used X-ray diffraction to reveal the  $m\text{-}t$  transformation, by observing the emergence of a  $(101)_t$  reflection with increasing Bi<sup>+</sup> dose. It should be noted, however, that this reflection can also be indexed as a  $(111)_c$  reflection from a cubic  $c\text{-}ZrO_2$  phase. Simeone et al. [7] employed Raman spectroscopy to eliminate this ambiguity and identified a small spectral feature at  $\sim 257\text{ cm}^{-1}$ , which can only be attributed to  $t\text{-}ZrO_2$ . Valdez et al. [8] demonstrated that 300 keV  $Kr^{++}$  ion irradiation of  $m\text{-}ZrO_2$  also produces

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**Fig. 1.** Schematic diagrams illustrating the relationship between the body-centered tetragonal (bct) and cubic (c) unit cells of  $\text{ZrO}_2$ . The atoms are shown in their ideal positions for a structure with cubic symmetry. The large spheres represent O anions; the small spheres represent Zr cations. The larger cubic unit cell is translated so that the cations appear 'edge-centered' with respect to the cube edges.

the  $m$ - $t$  transformation (this is in primarily a nuclear stopping regime). This phase change was characterized by Valdez et al. [8] using three characterization techniques, namely confocal Raman spectroscopy, grazing incidence X-ray diffraction and cross-sectional transmission electron microscopy. In other experiments using swift heavy ions (135 MeV  $^{58}\text{Ni}$ , 300 MeV  $^{76}\text{Ge}$  and 250 MeV  $^{127}\text{I}$ ), where primarily electronic stopping dominates over nuclear stopping, Benyagoub et al. [9–11], observed a similar  $m$ - $t$   $\text{ZrO}_2$  transformation, based on X-ray diffraction and Raman spectroscopy measurements. Most significantly, Benyagoub et al. [9] observed a prominent  $t$ - $\text{ZrO}_2$  Raman feature at  $\sim 265\text{ cm}^{-1}$  in  $\text{ZrO}_2$  irradiated with 300 MeV Ge ions.

In this report, we examine radiation damage effects in  $\text{ZrO}_2$  induced by noble gas,  $\text{Ne}^+$  ions. The purpose of this study is to assess further the sensitivity to spectrum effects of the  $m$ - $t$  transformation observed in previous irradiation damage studies of  $\text{ZrO}_2$ . The use of light  $\text{Ne}^+$  ions allows us to enhance the total ionization loss per unit damage energy, compared to the heavy ion,  $\text{Kr}^+$  irradiation experiments that we performed previously [8]. Zinkle [12–14] has shown that irradiation-induced microstructures in oxides such as  $\text{MgO}$ ,  $\text{Al}_2\text{O}_3$ , and  $\text{MgAl}_2\text{O}_4$  are influenced by irradiating ion mass, especially by corresponding variations in electronic-to-nuclear stopping power characteristics of the irradiation spectrum. In particular, enhanced electronic stopping was shown to suppress dislocation loop nucleation, while at the same time enhancing loop growth [12–14]. These effects were attributed to ionization-induced diffusion of point defects in these oxides [15]. The experimental results presented here will be examined for evidence of similar irradiation spectrum effects.

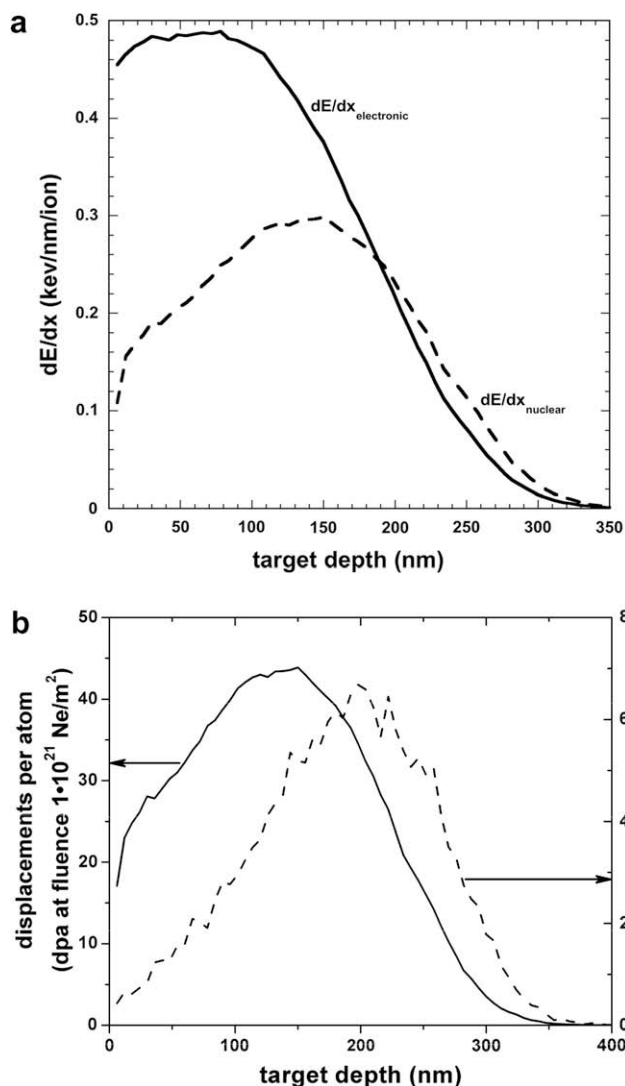
## 2. Experimental procedure

$\text{ZrO}_2$  powders supplied by CERAC Corp. (99.995% pure, 325 mesh) were hot-pressed in a graphite die at 24 MPa for 2.5 h at 2070 K. Hot-pressed sample densities were estimated geometrically to be  $\sim 98\%$  of the theoretical value. Samples cut from the

hot-pressed pucks were uniform black in color. The black color is usually indicative of oxygen deficiency. Thermal gravimetric analysis (TGA) revealed the stoichiometry to be  $\text{ZrO}_{1.98}$ . Sample wafers were polished using  $0.25\text{ }\mu\text{m}$  diamond impregnated lapping films to a mirror finish. A typical wafer dimension was  $10 \times 10 \times 0.5\text{ mm}$ . X-ray diffraction indicated that the as-prepared zirconia samples were nearly phase pure and possessed the monoclinic, baddeleyite structure. Analysis of the diffraction data revealed further that the monoclinic lattice parameters of the ' $\text{ZrO}_2$ ' are  $a = .5153 \pm 5\text{ nm}$ ,  $b = .5193 \pm 5\text{ nm}$ ,  $c = .5343 \pm 5\text{ nm}$ ,  $\beta = 99^\circ 38' \pm 10'$ , and the molecular volume is  $V_{\text{mol}} = 0.0352\text{ nm}^3/\text{ZrO}_2$ . This compares favorably with, for instance, refinement of high resolution neutron powder diffraction data obtained by Howard et al. [16] (also JCPDF file #78-1807 [17]) where the lattice parameters of  $m$ - $\text{ZrO}_2$  were found to be  $a = .51505(1)\text{ nm}$ ,  $b = .52116(1)\text{ nm}$ ,  $c = .53173(1)\text{ nm}$ ,  $\beta = 99.230(1)^\circ$ , which yields a molecular volume of  $V_{\text{mol}} = 0.0352\text{ nm}^3/\text{ZrO}_2$ . In addition, a  $t$ - $\text{ZrO}_2$  specimen was also prepared using co-precipitation procedures. The  $t$ - $\text{ZrO}_2$  phase was stabilized using 12 mol% Ce. This specimen was used as a standard for Raman spectroscopy measurements.

Zirconia samples were irradiated with 150 keV  $\text{Ne}^+$  ions in the Ion Beam Materials Laboratory at Los Alamos National Laboratory using a 200 kV Varian implanter. Ion fluences ranged from  $5 \times 10^{19}$  to  $1 \times 10^{21}\text{ Ne/m}^2$ . This fluence range was chosen to achieve similar displacement damage doses to those used in previous irradiation experiments performed by Valdez et al. using  $\text{Kr}^{++}$  ions [8]. All irradiations were performed using a liquid nitrogen-cooled specimen holder (sample temperature  $\sim 80\text{ K}$ ) and using a constant ion flux of  $1 \times 10^{16}\text{ Ne/m}^2\text{ s}$  (ion flux was kept as low as practically possible, in order to minimize sample heating effects). Fig. 2 shows characteristics of the 150 keV  $\text{Ne}^+$  ion implantation into  $m$ - $\text{ZrO}_2$ , obtained using the Monte Carlo ion transport code SRIM2000 [18] (displacement energies of 40 eV for Zr and O atoms and a density of  $8.8\text{ gm/cm}^3$  were used for these calculations). Fig. 2(a) shows estimates of energy loss partitioned into nuclear and electronic components for 150 keV Ne in  $m$ - $\text{ZrO}_2$ . Fig. 2(b) shows estimates of ballistic damage (in units of dpa) and implanted Ne atomic concentration as a function of depth into the target, for the highest fluence of  $1 \times 10^{21}\text{ Ne/m}^2$  used in these experiments.

Ion irradiation-induced damage was assessed using three materials characterization techniques: (1) transmission electron microscopy (TEM); (2) grazing incidence X-ray diffraction (GIXRD); and (3) Raman spectroscopy (RS). TEM observations were made using a Philips CM-30 instrument operating at 300 kV. GIXRD measurements were made using a Bruker AXS D8 Advance X-ray diffractometer,  $\text{Cu K}_\alpha$  radiation, and  $\theta$ - $2\theta$  geometry. The X-ray diffractometer was equipped with a Göebel mirror to achieve parallel beam diffraction optics. The  $\theta$ - $2\theta$  scans were performed using a step size of  $0.008^\circ$  and a dwell time of 1 s per step unless indicated otherwise. Three grazing angles of incidence,  $\gamma = 0.25^\circ$ ,  $0.5^\circ$  and,  $1.0^\circ$ , were used for GIXRD measurements, in such a way that the calculated X-ray penetration depths fell within the range of the implanted  $\text{Ne}^+$  ions in the  $\text{ZrO}_2$  target material. X-ray penetration depths can be estimated both geometrically (see, e.g., Rafaja et al. [19]) and based on critical angle, total external reflection (see, e.g., Guinier [20] and Lim [21]). Geometrically, the GIXRD penetration depth is given by  $\sin(\gamma) \sin(2\theta - \gamma) / (\mu(\sin(\gamma) + \sin(2\theta - \gamma)))$ , where  $\gamma$  is the X-ray angle of incidence,  $2\theta$  is the diffraction angle for the particular measurement, and  $\mu = 620\text{ cm}^{-1}$  is the linear absorption coefficient for  $\text{ZrO}_2$ . In terms of the critical angle for external reflection,  $\alpha_c$ , the GIXRD penetration depth is given by  $\lambda/2\pi(\alpha_c^2 - \gamma^2)^{1/2}$  for  $\gamma < \alpha_c$ , and by  $2\gamma/\mu$  for  $\gamma > \alpha_c$ , where  $\lambda$  is the X-ray wavelength and  $\alpha_c \cong \sqrt{2} \delta^{-3} \sqrt{\rho} \lambda$ , where  $\delta = (1 - \eta)$  for refractive index,  $\eta$  ( $\rho$  is the density of the material in  $\text{gm cm}^{-3}$  and  $\lambda$  is the X-ray wavelength in  $\text{\AA}$ ). Fig. 3 shows plots of GIXRD X-ray penetration in  $\text{ZrO}_2$ , based on these two methods of



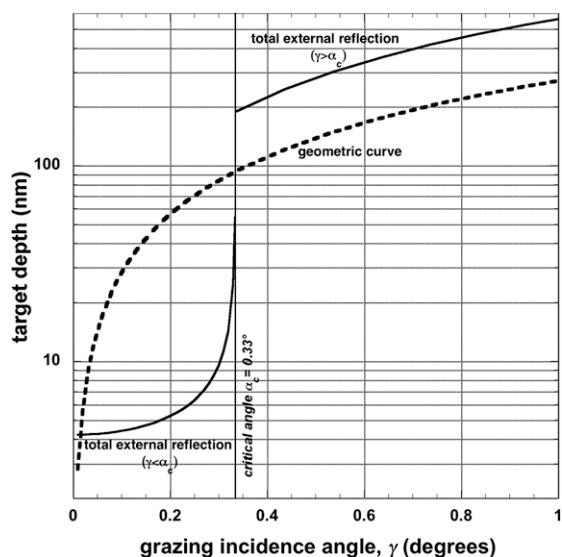
**Fig. 2.** SRIM simulation results for 150 keV  $\text{Ne}^+$  ion irradiation of  $\text{ZrO}_2$ . (a) Energy loss as a function of depth for the nuclear and electronic stopping components of the stopping power (energy partitioning includes both primary and secondary knock-on effects). (b) Displacement damage (left-hand ordinate) and implanted  $\text{Ne}^+$  ion concentration (right-hand ordinate) as a function of depth for  $\text{Ne}^+$  ion irradiation of  $\text{ZrO}_2$  to a fluence of  $1 \times 10^{21} \text{ Ne/m}^2$ .

calculation. Comparing Figs. 2(b) and 3, it is clear that GIXRD patterns obtained with  $\gamma = 0.25^\circ$  probe the uppermost portion of the implanted layer, patterns obtained with  $\gamma = 0.5^\circ$  probe from the surface to the maximum in the displacement damage profile and possibly beyond, and patterns obtained with  $\gamma = 1.0^\circ$  probe the entire implanted region, in addition (perhaps) to some unirradiated substrate material. To keep effects from the implanted  $\text{Ne}^+$  and unirradiated substrate material and to a minimum, GIXRD measurement results discussed later were all collected using the grazing incidence angle of  $\gamma = 0.25^\circ$ .

RS measurements were obtained using a confocal Renishaw Raman Microprobe 1000. A 488 nm wavelength excitation at 3 mW of power was used (argon ion laser) and a count time of 10 s at focus with a  $50\times$  objective lens.

### 3. Results

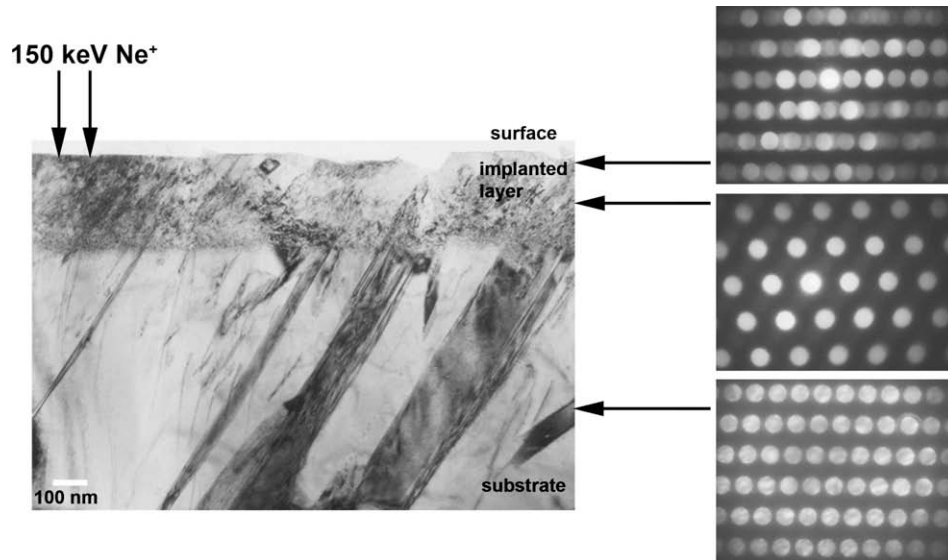
Fig. 4 shows a bright-field TEM micrograph obtained in cross-sectional geometry from  $m\text{-ZrO}_2$  irradiated with 150 keV  $\text{Ne}^+$  ions to a fluence of  $5 \times 10^{20} \text{ Ne/m}^2$ . The area imaged shows a portion



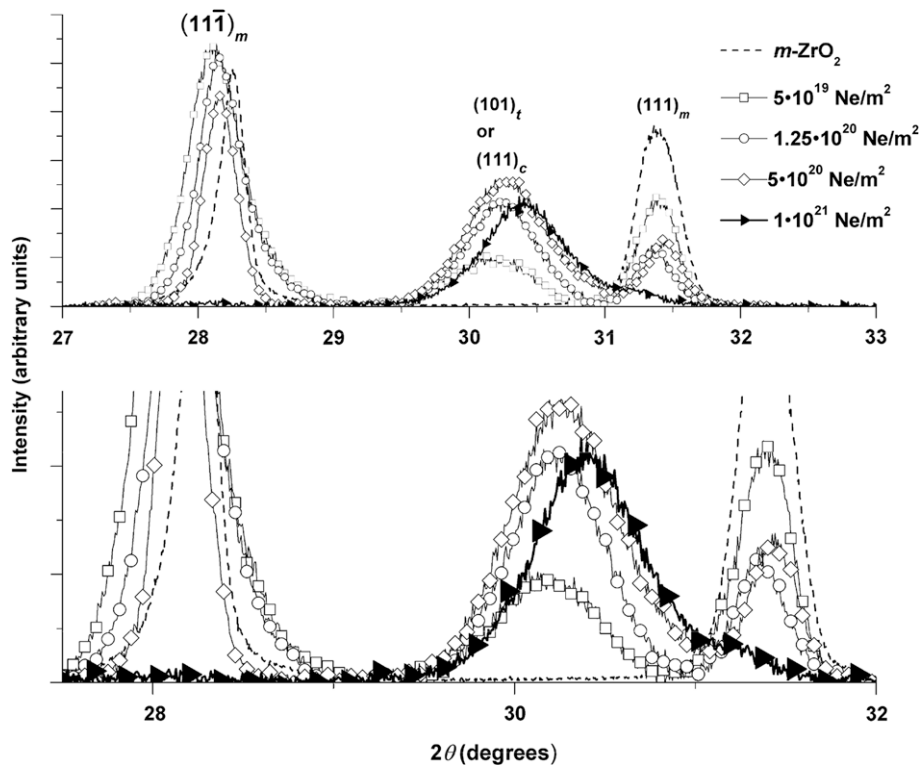
**Fig. 3.** Grazing incidence X-ray diffraction (GIXRD) X-ray penetration depth versus grazing incidence angle ( $\gamma$ ), calculated using two different methods (see text for discussion).

of a single grain in the unirradiated substrate along with several twins (twins are expected for monoclinic zirconia processed under our sintering conditions). The thickness of the irradiated layer in the image is 280 nm, which (surprisingly) is somewhat narrower than the 350 nm predicted by SRIM (Fig. 2). The irradiated layer consists of very fine grains (nano-sized) and diffraction contrast arising from a high concentration of irradiation-induced defects. Fig. 4 also shows microdiffraction patterns ( $\mu\text{D}$ ) obtained from upper and lower portions of the irradiated layer and from the unirradiated substrate. Indexing of the uppermost diffraction pattern revealed that the upper portion of the irradiated layer consists of both monoclinic and tetragonal  $\text{ZrO}_2$  reflections while the bottom of the layer exhibits only tetragonal reflections. The incident beam direction in the lower portion of the irradiated layer is consistent with  $\bar{\mathbf{B}} = [111]_t$ . The microdiffraction pattern from the substrate can be indexed as a monoclinic structure, with an incident beam direction given by  $\bar{\mathbf{B}} = [1\bar{1}0]_m$ . We note that our  $\mu\text{D}$  results do not establish unambiguously the presence of  $t\text{-ZrO}_2$  in the irradiated layer. The  $\mu\text{D}$  patterns shown in Fig. 4 can likewise be indexed as arising from a cubic,  $c\text{-ZrO}_2$  structure. Additional characterization measurements were performed to resolve this ambiguity.

Fig. 5 shows GIXRD patterns obtained from both unirradiated  $m\text{-ZrO}_2$  and  $\text{ZrO}_2$  irradiated with 150 keV  $\text{Ne}^+$  ions to fluences ranging from  $5 \times 10^{19}$  to  $1 \times 10^{21} \text{ Ne/m}^2$ . Before irradiation, the principal diffraction maxima in the region of  $2\theta$  shown in Fig. 5 are readily indexed as  $(111)_m$  and  $(111)_m$  reflections from  $m\text{-ZrO}_2$ . Following  $\text{Ne}^+$  ion irradiation, the monoclinic peaks are diminished in intensity and a new peak emerges at about  $2\theta = 30.25^\circ$ . This peak shifts to larger  $2\theta$  with increasing ion fluence, indicating a contraction of the lattice planes belonging to this new phase. The appearance of this new peak indicates a change in crystal structure of the irradiated  $m\text{-ZrO}_2$ . However, this peak can be indexed as either a  $(101)_t$  or  $(111)_c$  reflection, corresponding to  $t\text{-ZrO}_2$  or  $c\text{-ZrO}_2$  structures, respectively. GIXRD measurements in this  $2\theta$  range do not unambiguously distinguish between such  $m\text{-t}$  or  $m\text{-c}$  transformations. This ambiguity has been discussed previously in the literature (see, e.g., Refs. [5,9]). To resolve this uncertainty, we performed GIXRD scans in the angular range from  $42^\circ \leq 2\theta \leq 44^\circ$  in order to assess the presence or absence of a  $(102)_t$  reflection. The structure factor for  $c\text{-ZrO}_2$  is zero in this angular range. These scans were performed slowly (25 s/step)



**Fig. 4.** Bright-field transmission electron microscopy (TEM) micrograph obtained from a cross-sectional sample of  $\text{ZrO}_2$  irradiated with 150 keV  $\text{Ne}^+$  ions to a fluence of  $5 \times 10^{20} \text{ Ne/m}^2$ . Also shown are microdiffraction ( $\mu\text{D}$ ) patterns obtained from small regions ( $<10 \text{ nm}$  diameter) of the ion irradiated layers (top/middle patterns) and the unirradiated substrate (bottom pattern). The incident electron beam direction for the substrate  $\mu\text{D}$  pattern is  $\mathbf{B} = [1\bar{1}0]_m$ .



**Fig. 5.** GIXRD patterns obtained from pristine  $m\text{-ZrO}_2$  and  $\text{ZrO}_2$  irradiated with 150 keV  $\text{Ne}^+$  ions to fluences ranging from  $5 \times 10^{19}$  to  $1 \times 10^{21} \text{ Ne/m}^2$ . The angle of incidence of the X-ray beam was fixed at  $\gamma = 0.25^\circ$ . The upper profiles were obtained over the diffraction angular range  $27^\circ \leq 2\theta \leq 33^\circ$ . The lower profiles are the same patterns in the range  $27.5^\circ \leq 2\theta \leq 32^\circ$ , expanded along the ordinate to emphasize the weaker diffracted intensities.

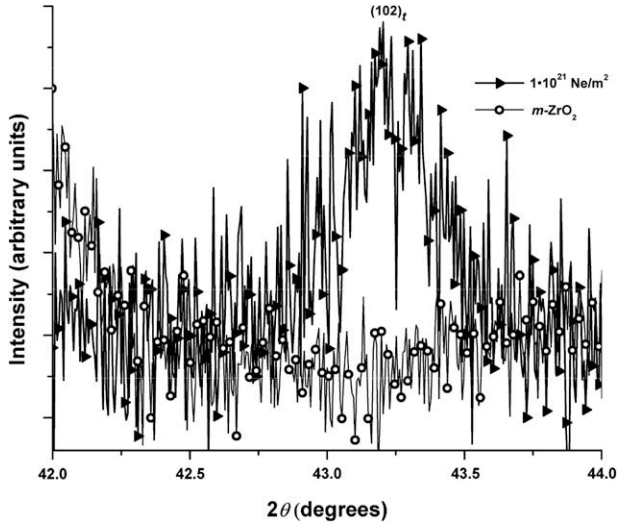
because the predicted intensity for the  $(102)_t$  reflection is extremely small (1% of the 100%  $t\text{-ZrO}_2$  peak). Fig. 6 shows GIXRD patterns obtained from unirradiated  $m\text{-ZrO}_2$  and  $\text{ZrO}_2$  irradiated to a fluence of  $1 \times 10^{21} \text{ Ne/m}^2$ , using  $\gamma = 0.25^\circ$ . Unirradiated  $m\text{-ZrO}_2$  shows no diffraction features in this range. But in the  $\text{Ne}^+$  ion irradiated material, a small peak is apparent at  $2\theta \sim 43.2^\circ$ . The position of this new peak is consistent with the  $(102)_t$  reflection position for  $t\text{-ZrO}_2$  reported by Málek et al. [22] and JCPDF file #50-1089

[17] (the latter reference places the  $(102)_t$  reflection at  $2\theta = 43.140^\circ$  for  $\text{Cu K}_\alpha$  radiation). Thus, GIXRD provides experimental evidence to support an  $m \rightarrow t$  transformation of  $\text{ZrO}_2$  induced by  $\text{Ne}^+$  ion irradiation.

The  $t\text{-ZrO}_2$  lattice parameters and molecular volume for the highest ion dose used here (fluence  $1 \times 10^{21} \text{ Ne/m}^2$ ) were determined to be  $a = 0.3574 \pm 5 \text{ nm}$ ,  $c = 0.5177 \pm 5 \text{ nm}$ ,  $V_{\text{mol}} = 0.03306 \text{ nm}^3/\text{ZrO}_2$ , based on Gaussian curve fits to the observed GIXRD



peaks. These values are in good agreement with those for the tetragonal phase reported by Málek et al. [22] for a metastable,

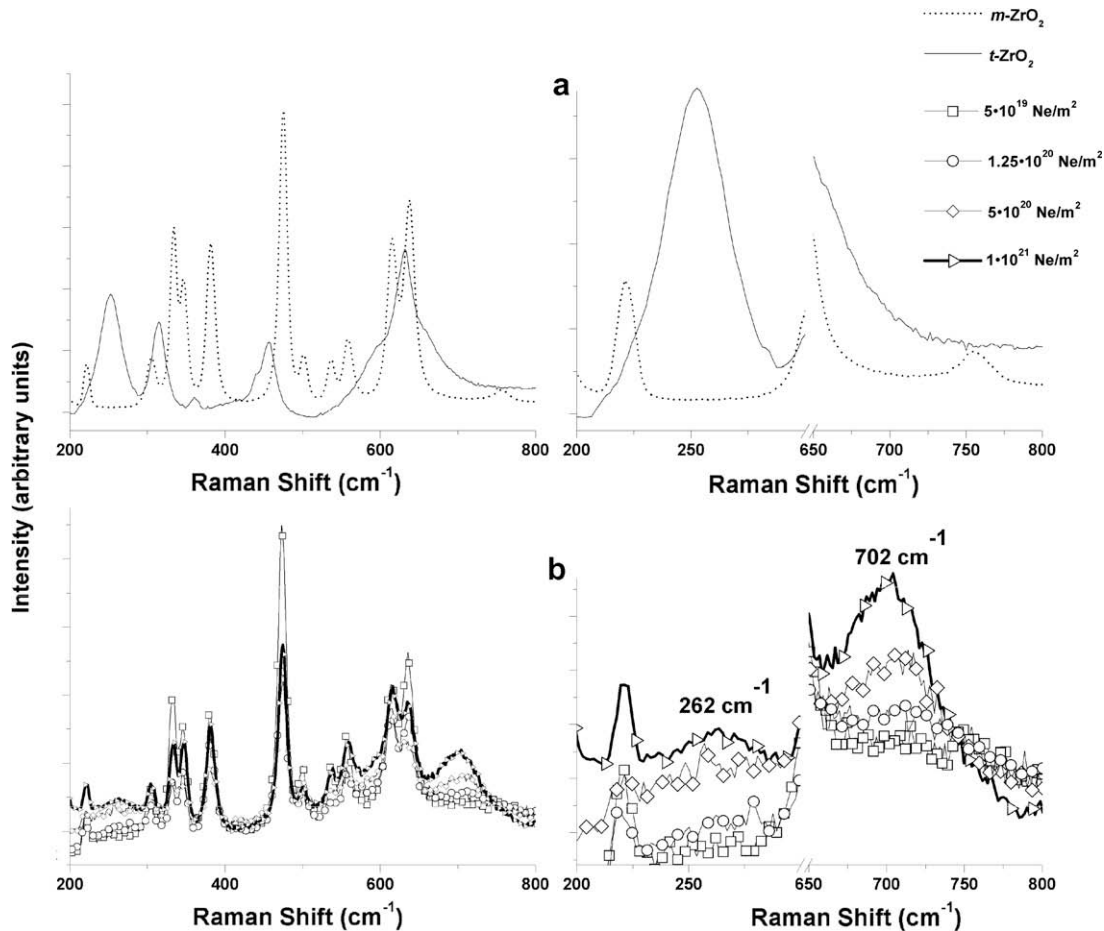


**Fig. 6.** GIXRD patterns obtained from pristine *m*-ZrO<sub>2</sub> and ZrO<sub>2</sub> irradiated with 150 keV Ne<sup>+</sup> ions to a fluence of  $1 \times 10^{21}$  Ne/m<sup>2</sup>. The patterns show the diffraction angular range  $42^\circ \leq 2\theta \leq 44^\circ$ . The angle of incidence of the X-ray beam was fixed at  $\gamma = 0.25^\circ$ . Scan obtained using a dwell time of 25 s per step.

low temperature *t*-ZrO<sub>2</sub> phase, specifically,  $a = 0.35984(5)$  nm,  $c = 0.5152(1)$  nm,  $V_{\text{mol}} = 0.03335$  nm<sup>3</sup>/ZrO<sub>2</sub>. Differences may be attributed both to differences in sample stoichiometry and to stresses induced in the irradiated sample surface layers in these experiments.

Fig. 7 shows RS spectra obtained from both *m*-ZrO<sub>2</sub>, *t*-ZrO<sub>2</sub>, and ZrO<sub>2</sub> irradiated with Ne<sup>+</sup> ions to fluences ranging from  $5 \times 10^{19}$  to  $1 \times 10^{21}$  Ne/m<sup>2</sup>. Fig. 7(a) shows RS spectra obtained from a pristine *m*-ZrO<sub>2</sub> sample and from a Ce-stabilized, *t*-ZrO<sub>2</sub> standard specimen. Fig. 7(b) shows RS data obtained from ZrO<sub>2</sub> irradiated with Ne<sup>+</sup> ions to successively higher fluences. The irradiated RS spectra in Fig. 7(b) show the gradual appearance of a faint band at  $\sim 262$  cm<sup>-1</sup>, a band not present in the RS spectrum obtained from the unirradiated sample. With increasing Ne<sup>+</sup> ion fluence, this peak increases in resolution and intensity. This Raman shift position corresponds well with the most intense band in the RS spectrum obtained from the Ce-stabilized *t*-ZrO<sub>2</sub> control sample (Fig. 7(a)). This faint band was previously observed in ion irradiated ZrO<sub>2</sub> samples [7–9] and was attributed to a tetragonal zirconia phase produced by ion irradiation.

Another RS band centered at 702 cm<sup>-1</sup> also grows in intensity with increasing Ne<sup>+</sup> ion fluence (Fig. 7(b)). Comparing the RS standard spectra (Fig. 7(a)) to the irradiated RS spectra (Fig. 7(b)), it is clear that there are no bands belonging to either *m*-ZrO<sub>2</sub> or *t*-ZrO<sub>2</sub> coinciding with the position of this new band. It is interesting to note that we also observed this same band with similar shape and intensity in an RS spectrum obtained from a ZrO<sub>2</sub> sample irra-



**Fig. 7.** (a) Raman spectroscopy (RS) spectra obtained from pristine *m*-ZrO<sub>2</sub> (dotted line) and from a Ce-stabilized, *t*-ZrO<sub>2</sub> standard specimen (solid line). Spectra on the right are the same as those on the left, but expanded along the ordinate to enhance details of weaker RS features. (b) RS spectra obtained from ZrO<sub>2</sub> irradiated with 150 keV Ne<sup>+</sup> ions over a fluence range of  $5 \times 10^{19}$ – $1 \times 10^{21}$  Ne/m<sup>2</sup>. Spectra shown on the right are the same as those shown on the left, with the ordinate expanded to show additional details in the smaller RS bands. Two new bands appear at  $\sim 262$  and  $\sim 702$  cm<sup>-1</sup> following ion irradiation.

diated with 300 keV  $\text{Kr}^{++}$  ions to a fluence of  $1 \times 10^{20} \text{ Kr/m}^2$  (data not shown here; sample from the study in Ref. [8]). This new band may be due to another phase of zirconia. To test this hypothesis, we also acquired an RS spectrum from a sample of yttria-stabilized cubic zirconia, but we observed no features in the spectral vicinity of  $700 \text{ cm}^{-1}$  (data not shown). We are continuing to investigate the origin of this mystery RS band.

#### 4. Discussion

Based on the results presented here, we conclude that  $m\text{-ZrO}_2$  undergoes a monoclinic-to-tetragonal,  $m\text{-}t$  transformation to a  $t\text{-ZrO}_2$  phase when irradiated with 150 keV  $\text{Ne}^+$  ions at cryogenic temperature. The  $m\text{-}t$  transformation found here is consistent with findings in several previous ion irradiation damage studies [7–11]. In addition, the new tetragonal phase is very stable, based on GIXRD measurements taken 550 days after  $\text{Ne}^+$  ion irradiations. GIXRD patterns on aged specimens also showed almost no change in either  $t\text{-ZrO}_2$  phase concentration or molecular volume.

Fig. 8 shows results of an attempt to estimate the  $\text{Ne}^+$  ion-induced  $m\text{-}t$  transformation rate, based on GIXRD results presented in the previous section (using X-ray incidence angle,  $\gamma = 0.25^\circ$ ). In Fig. 8, the percentage of  $m\text{-ZrO}_2$  transformed to  $t\text{-ZrO}_2$  ( $t\%$ ) was estimated using the following formula from Garvie and Nicholson [23]:  $t\% = I(101)_t / (I(111)_m + I(111)_m + I(101)_t)$ , where  $I$  represents the integrated peak area for a specific reflection. These calculations suggest that the tetragonal phase transformation progressed to a maximum of approximately 85% at the maximum experimental fluence of  $1 \times 10^{21} \text{ Ne/m}^2$ . Fig. 8 also shows that the  $d$ -spacing belonging to the  $(101)_t$  family of  $t\text{-ZrO}_2$  planes decreases with increasing  $\text{Ne}^+$  fluence, with a measured contraction of  $\sim 0.72\%$  by the maximum fluence of  $1 \times 10^{21} \text{ Ne/m}^2$ . We speculate that higher doses may lead to further volume contraction, such that the material approaches a structure indistinguishable from a cubic fluorite ( $c\text{-ZrO}_2$ ).

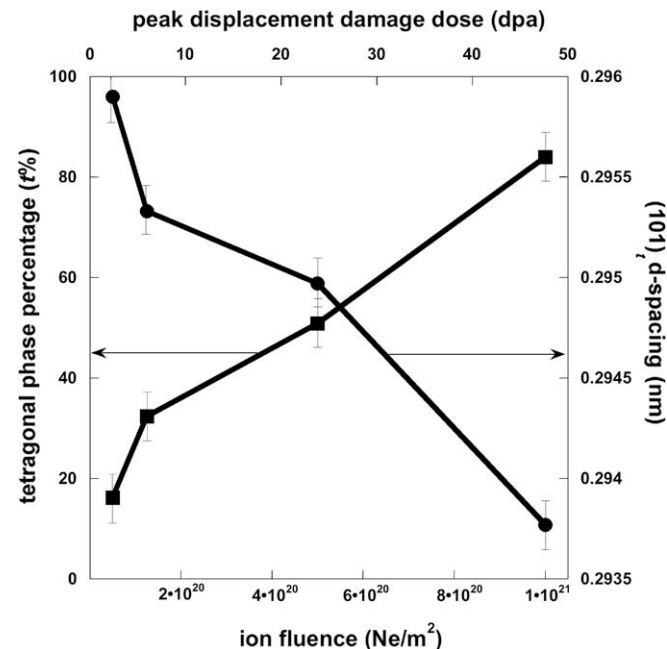


Fig. 8.  $\text{ZrO}_2$  tetragonal ( $t$ ) phase evolution and evolution of the  $d$ -spacing belonging to the  $(101)_t$  family of  $t\text{-ZrO}_2$  planes, as a function  $\text{Ne}^+$  ion fluence. These results are based on GIXRD measurements using an X-ray incidence angle, of  $\gamma = 0.25^\circ$  (see text for discussion).

Interestingly, the rate of transformation from  $m\text{-ZrO}_2$  to  $t\text{-ZrO}_2$  observed in these  $\text{Ne}^+$  ion irradiation experiments is slower compared to our previously published  $\text{Kr}^+$  ion irradiation results [8], when the transformation rate is normalized with respect to the nuclear stopping component of the ion energy loss. Fig. 9 shows the transformation percentage ( $t\%$ ) for  $\text{Ne}^+$  versus  $\text{Kr}^+$  ion irradiation as a function of dpa ( $\text{Ne}^+$  results from Fig. 8;  $\text{Kr}^+$  results from Ref. [8]). These results indicate that  $m\text{-ZrO}_2$  exhibits a sensitivity to irradiation spectrum. Fig. 10 shows how the electronic-to-nuclear stopping power (ENSP) ratio varies as a function of depth in a  $\text{ZrO}_2$  target for 150 keV  $\text{Ne}^+$  versus 300 keV  $\text{Kr}^{++}$  ions (based on

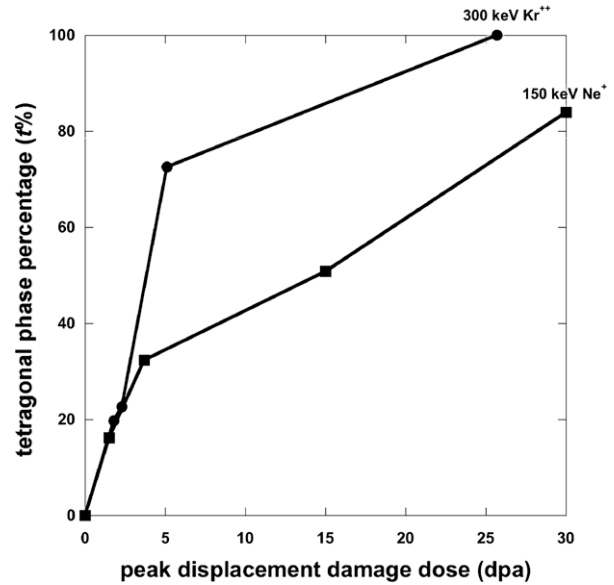


Fig. 9. Tetragonal ( $t$ ) phase evolution as a function of displacement damage dose for 150 keV  $\text{Ne}^+$  versus 300 keV  $\text{Kr}^{++}$  ion irradiations of  $\text{ZrO}_2$ . These results are based on GIXRD measurements of  $\text{Ne}^+$  ion irradiated samples from this study and on  $\text{Kr}^{++}$  ion irradiated samples from Valdez et al. [8].

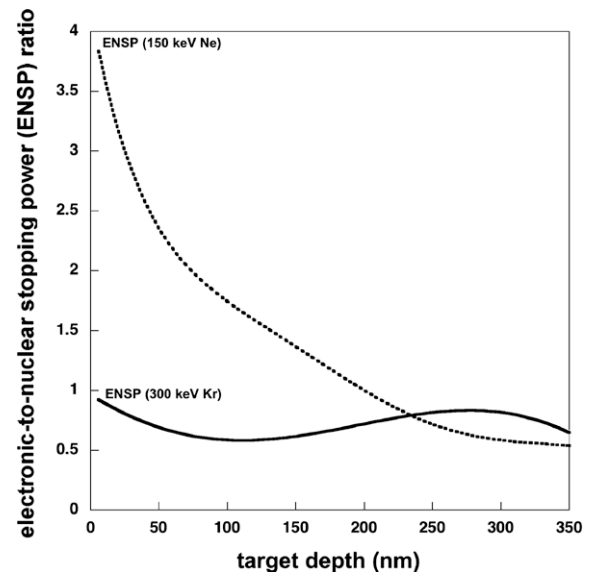


Fig. 10. SRIM simulation results comparing the electronic-to-nuclear stopping power (ENSP) ratio for 150 keV  $\text{Ne}^+$  versus 300 keV  $\text{Kr}^{++}$  ion irradiated of  $\text{ZrO}_2$  as a function of depth. The variation in ENSP as a function of depth for the 300 keV  $\text{Kr}^{++}$  ions is not statistically significant (the uncertainty in ENSP is  $\pm 0.25$ ).

SRIM-2000 ion stopping simulations). Fig. 10 indicates that ENSP is significantly larger for 150 keV Ne<sup>+</sup> ions compared to 300 keV Kr<sup>+</sup> ions throughout most of the range of both ions. ENSP for 150 keV Ne<sup>+</sup> ions exhibits a maximum of  $\sim 4.5$  near the sample surface and is greater than 1 to a depth of  $\sim 200$  nm. On the contrary, ENSP for 300 keV Kr<sup>+</sup> ions is less than 1 over the entire ion range. One explanation for the more sluggish  $m$ - $t$  transformation rate observed for Ne<sup>+</sup> ion irradiations may be that the greater ionization loss per unit damage energy leads to enhanced ionization-induced point defect diffusion, which in turn promotes recombination of the defects responsible for the  $m$ - $t$  transformation.

In accordance with typical materials behavior under irradiation, the ion irradiation-induced phase transformation of zirconia described here involves a transition to a structure of higher crystal symmetry (tetragonal versus monoclinic). Somewhat surprisingly, however, radiation damage studies of zirconia thus far have failed to reveal a transformation to the highest symmetry polymorph of zirconia, the cubic fluorite phase. So, even though unstabilized zirconia has proven highly resistant to amorphization, it manages this without adopting the structure of the highest symmetry polymorph of ZrO<sub>2</sub>, the isometric cubic structure. On the contrary, a crystalline asymmetry persists in irradiated zirconia to very high levels of radiation damage. The prediction by Sickafus et al. [24] of a transformation to the cubic, fluorite-structured phase of zirconia is not realized under the radiation damage conditions presented here. Nevertheless, it still seems plausible that an  $m$ - $t$ - $c$  transformation may occur at higher ion doses, as we find that the  $t$ -ZrO<sub>2</sub> molecular volume continues to contract with increasing ion fluence.

It is interesting that irradiation produces a tetragonal phase with a higher density than that of the parent monoclinic phase. Comparing pristine  $m$ -ZrO<sub>2</sub> with irradiation-induced  $t$ -ZrO<sub>2</sub>, we find that the volume per molecule of ZrO<sub>2</sub> decreases from .0352 to .0329 nm<sup>3</sup> upon undergoing the irradiation-induced  $m$ - $t$  transformation (the value for  $t$ -ZrO<sub>2</sub> is for the highest ion irradiation dose used in these experiments). This represents approximately a 6.5% increase in density for this irradiation-induced transformation. This density increase may be compared with density differences for  $m$ -ZrO<sub>2</sub> [16] and low temperature metastable  $t$ -ZrO<sub>2</sub> [21], which differ in density by  $\sim 5.6\%$  ( $t$ -ZrO<sub>2</sub> being the higher). The density increase observed here was also observed in our previous investigation of irradiation effects in  $m$ -ZrO<sub>2</sub> using 300 keV Kr<sup>++</sup> ions [8]. Interestingly, we also recently observed an increase in density upon phase transformation in Kr<sup>++</sup> ion irradiated Dy<sub>2</sub>O<sub>3</sub> [25]. It should be noted that fused (vitreous) silica densifies during irradiation near room temperature to form a higher density amorphous silica phase [26], but the lattice contraction observations described above may be the first observations of such behavior in crystalline solids during irradiation.

It is also well known from detailed studies of the crystallography of the various polymorphs of zirconia that the  $m$ - $t$  transformation is accompanied by an increase in coordination of the Zr atoms from 7- to 8-fold (see, e.g., Ref. [27]). This also would seem a surprising materials' response to irradiation, although the effect is not unprecedented. The irradiation-induced phase transformation we observed previously in the sesquioxide dysprosia, Dy<sub>2</sub>O<sub>3</sub>, shares a similar characteristic [25]: namely, an increase in cation coordination upon irradiation from 6-fold to a mixture of 6- and 7-fold.

A final consideration for discussion is the possibility for experimental artifacts associated with near-surface ion implantation. First is the possibility that the lattice contraction we observed with increasing ion dose may be due to implanted ions. We believe this should not be the case since the implanted Ne ions should promote lattice expansion, not shrinkage. The second possibility is that the  $m$ - $t$  transformation observed here could be due to compressive lattice stress in the irradiated region, associated with the high

concentration of implanted Ne ions (up to 6 at.% Ne for the highest dose (Fig. 2)). It has already been shown that stress can increase dramatically with increasing implanted ion concentration (see, e.g., Ref. [28]). But if the transformation we observe is stress-induced, we might expect a high-pressure polymorph of zirconia to emerge with increasing dose, rather than a high-temperature polymorph. Of the known high-pressure phases of zirconia, three (and perhaps a fourth) are orthorhombic [29], while there is some controversy about an additional tetragonal phase [30]. However, the latter phase was determined to have lattice parameters and symmetry elements far different from the tetragonal phase we observed in this study. Nevertheless, since these high-pressure phases may be kinetically inhibited from forming under our cryogenic irradiation conditions, a stress-induced mechanism for the  $m$ - $t$  transformation cannot be ruled out.

## 5. Summary

Polycrystalline samples of monoclinic zirconia (specifically, ZrO<sub>1.98</sub>) were irradiated at cryogenic temperature ( $\sim 80$  K) with 150 keV Ne<sup>+</sup> ions over a range of ion fluences from  $5 \times 10^{19}$  to  $1 \times 10^{21}$  Ne/m<sup>2</sup> (this fluence range corresponds to peak displacement damage doses ranging from 2 to 44 dpa). Transmission electron microscopy observations revealed that at an ion fluence of  $5 \times 10^{20}$  Ne/m<sup>2</sup>, the buried irradiated region was completely transformed from a monoclinic ( $m$ ) structure to a tetragonal ( $t$ ) structure of ZrO<sub>2</sub>, while the upper, near-surface irradiated region consisted of a mixture of  $m$  and  $t$ -phases. Grazing incidence X-ray diffraction measurements were used to estimate the percentage of  $t$ -phase produced by ion irradiation. It was found that at the highest ion fluence of  $1 \times 10^{21}$  Ne/m<sup>2</sup>, the irradiated zirconia was approximately 85% transformed to the  $t$ -phase. The irradiation-induced transformation rate observed here is somewhat more sluggish than the rate observed in previous experiments using 300 keV Kr<sup>++</sup> irradiating ions [8], when the transformation rate is normalized in terms of the nuclear energy deposition. This suggests that electronic and nuclear stopping both play a role in the  $m$ - $t$  transformation and in recovery to the  $m$ -phase. The X-ray diffraction measurements also revealed that a significant increase in density ( $\sim 6.5\%$ ) accompanies the  $m$ - $t$  irradiation-induced transformation. Raman spectroscopy also provided evidence for the  $m$ - $t$  irradiation-induced transformation. Finally, it is worth noting that in this study, no evidence was found for transformation to the cubic ( $c$ ) phase, nor was any amorphization transformation observed.

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